## Valence force model for phonons in graphene and carbon nanotubes

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Many calculations require a simple classical model for the interactions between  $sp^2$ -bonded carbon atoms, as in graphene or carbon nanotubes. Here we present a valence force model to describe these interactions. The calculated phonon spectrum of graphene and the nanotube breathing-mode energy agree well with experimental measurements and with *ab initio* calculations. The model does not assume an underlying lattice, so it can also be directly applied to distorted structures. The characteristics and limitations of the model are discussed.

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Graphene and carbon nanotubes are remarkable materials, notable for both their fascinating properties and their technological promise.<sup>1</sup> In both contexts, it is often necessary to calculate the phonons for problems where the use of *ab initio* methods is not feasible. For graphitic systems, this has usually been approached by approximating the force-constant matrix with terms coupling atoms up to some maximum distance.<sup>2–8</sup> This approach has many appealing features, but it has two important limitations. First, the terms in the forceconstant matrix decay smoothly with distance between atoms,<sup>9</sup> so in practice it is necessary to truncate the expansion long before it has converged. Second, this approach is generally restricted to describing phonons in the ideal crystal. It has required some ingenuity and inconvenience even to extend these models to nanotubes, based on an idealized curved-graphene structure.<sup>3–6</sup>

In order to treat phonons in large low-symmetry systems, such as rumpled graphene or bent nanotubes, one would like a model that explicitly gives the energy as a function of atomic positions, without reference to any underlying crystal structure. In principle one could use the general-purpose empirical interatomic potentials that are available for carbon, such as Ref. 10. But phonon applications typically require higher accuracy than such general-purpose models can provide.

For diamond- and zinc-blende-structure semiconductors, the problem was largely solved by the use of "valence force" models. These models use a smaller number of more complex terms, which may be more or less physically motivated.<sup>11</sup> However, to date only one valence force model has been proposed for graphene;<sup>12,13</sup> and it explicitly references the graphene lattice, hindering application to distorted structures.<sup>14</sup>

Here we present a valence force model for  $sp^2$ -bonded carbon. The model explicitly gives energy as a function of atomic positions, without reference to any underlying crystal structure. The only restriction is that the local geometry be consistent with  $sp^2$  bonding, i.e., three neighbors not too far from 120° apart. Thus it can be directly applied not only to graphene but also to nanotubes and fullerenes, in relaxed or distorted configurations. We have tested the model for phonons in graphene and carbon nanotubes. We first describe the model itself and the fitting procedure. We then present and discuss the phonon spectrum, which is obtained after fitting the model parameters to selected experimental and theoretical data. Finally we discuss the overall accuracy and limitations, along with some related issues such as anharmonicity.

We write the energy as

$$\begin{split} E &= \beta_{r1} r_0^{-2} \sum_{i,j \in i} (\delta r_{ij})^2 + \beta_c \sum_{i,j < k \in i} (\delta c_{i,jk})^2 \\ &+ \beta_v r_0^{-2} \sum_{i,j < k < l \in i} \left( \frac{3 v_{ij} \cdot v_{ik} \times v_{il}}{r_{ij} r_{ik} + r_{ik} r_{il} + r_{il} r_{ij}} \right)^2 \\ &+ \beta_{r2} r_0^{-2} \sum_{i,j < k \in i} (\delta r_{ij}) (\delta r_{ik}) + \beta_p \sum_{i,j \in i} |\pi_i \times \pi_j|^2 \\ &+ \beta_{rc} r_0^{-1} \sum_{i,j \neq k < l \in i} (\delta r_{ij}) (\delta c_{i,kl}), \end{split}$$
(1)

where  $v_{ij}=v_j-v_i$ , with  $v_i$  being the atomic position vector of atom *i* and the bondlength is  $r_{ij}=|v_{ij}|$ . In the summations,  $j \in i$  means *j* runs over three neighbors of atom *i*,  $j < k \in i$ means *j* and *k* are both neighbors of *i* (ordered to avoid double counting), restriction j < k < l leaves only one possibility for the three neighbors of *i*, while restriction  $j \neq k < l$ gives three terms for each *i*.

The bond length in the ground state of graphene is  $r_0=0.142$  nm;  $\delta r_{ii}=r_{ii}-r_0$ . We further define

$$\delta c_{i,jk} = \frac{1}{2} + \frac{v_{ij} \cdot v_{ik}}{r_{ij}r_{ik}},$$

$$= 3 \frac{v_{ij} \times v_{ik} + v_{ik} \times v_{il} + v_{il} \times v_{ij}}{r_{ij}r_{ik} + r_{ik}r_{il} + r_{il}r_{ij}},$$
(2)

where j, k, and l are the three neighbors of i.

 $\pi_i$ 

The first two terms in Eq. (1) represent the bondstretching stiffness  $\beta_{r1}$  and bending stiffness  $\beta_c$ , as in the Keating model.<sup>15</sup> However, the form here avoids the large and unphysical anharmonicities of the Keating model. The third term  $\beta_v$  provides stiffness against out-of-plane vibrations. The fourth term  $\beta_{rc}$  is motivated by bond-order potentials.<sup>10</sup> The fifth term  $\beta_p$  gives stiffness against misalignment of neighboring  $\pi$  orbital. The last term  $\beta_{rc}$  couples bond stretching and bond bending.

In fitting such a model, one typically chooses a set of data that one desires to reproduce and defines a weighted error, which is to be minimized. As a straightforward test of the model and its ability to reproduce realistic phonon dispersions, we first try fitting to published local-density approxi-

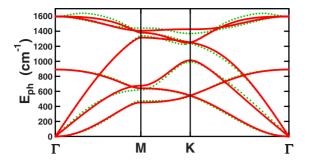


FIG. 1. (Color online) Phonon band dispersions. Green dotted curves are LDA calculations (Ref. 7). Red solid curves are results of the model [Eq. (1)] fitted to these LDA calculations. The corresponding parameters are given in Ref. 16.

mation (LDA) calculations.<sup>7,16</sup> The result is shown in Fig. 1. [We follow the spectroscopic convention of reporting phonon energies in cm<sup>-1</sup>, where 1 cm<sup>-1</sup> means  $hc/(1 \text{ cm}) \approx 0.124 \text{ meV.}$ ] The rms error is only 22.6 cm<sup>-1</sup>, substantially less than the best previous fit to GGA dispersions using a valence force model with five parameters.<sup>13</sup>

By giving more weight to one feature or another in the fitting, it is straightforward to improve the description of, e.g., the acoustic branches at the cost of worsening the optical branches. However, regardless of how we weighted the data, we could not reproduce the dips in the highest phonon bands at  $\Gamma$  and K while keeping a reasonable overall dispersion. This issue was also mentioned in Ref. 13. Electronphonon interactions are known to affect phonon dispersions even in bulk semiconductors,<sup>9</sup> and such interactions are particularly important for the highest bands of graphene near  $\Gamma$ and K due to the Kohn anomaly.<sup>17</sup> Thus we cannot expect to describe these dips with short-range classical interactions. It would therefore seem logical to fit the bands away from  $\Gamma$ and K and accept that the model gives energies that are too high for the top bands at those points. However, because the optical phonon energy at  $\Gamma$  is a widely used reference, we have chosen to fit this point accurately.

We find that the Poisson ratio calculated with our model fitted to the LDA calculations alone is  $\nu=0.4$ , larger than the experimental value of  $\nu=0.17$ . This suggests that elastic properties should be included in the fitting. Also, the experimental and theoretical data are not in perfect accord. We have therefore chosen to fit a mixture of published experimental phonon data, *ab initio* phonon calculations, and elastic constants. The resulting parameter values are listed in Table I, and the corresponding phonon dispersion is shown as a solid curve in Fig. 2. The corresponding elastic constants are given in Table II. (We equate in-plane elastic properties of graphene and graphite using the experimental layer spacing c=6.7 Å and volume per atom  $V_0=3\sqrt{3}r_0^2c/8$ .)

TABLE I. Parameters of the model [Eq. (1)] used in Fig. 2 based on best fit to the experimental data and LDA calculations. Units are in eV.

$\beta_{r1}$	$eta_c$	$eta_v$	$\beta_{r2}$	$oldsymbol{eta}_p$	$\beta_{rc}$
18.52	4.087	1.313	4.004	0.008051	4.581

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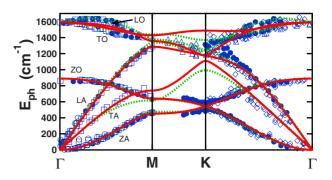


FIG. 2. (Color online) Phonon band dispersion, comparing fitted model with experimental data and *ab initio* calculations. Red solid curve is our model [Eq. (1)] with the parameters given in Table I. Green dotted curve is an LDA calculation (Ref. 7). Blue symbols are experimental data: electron energy-loss spectroscopy from Refs. 18–20 (respectively, squares, diamonds, and filled circles), neutron scattering from Ref. 21 (open circles), and x-ray scattering from Ref. 22 (triangles). Data for Refs. 18–22 are taken from Ref. 23.

Overall we consider the agreement in Fig. 2 and Table II to be quite good. The quality of the fit is a highly nonlinear function of the parameters, so there may be entirely different sets of parameters that give a similar or even better agreement with the same data.

The longitudinal and transverse sound velocities  $(v=d\omega/dq \text{ at } q=0)$  within our model are

$$M_{C}v_{T}^{2} = \frac{81}{4} \frac{4\beta_{r1}\beta_{c} - 2\beta_{r2}\beta_{c} - \beta_{rc}^{2}}{12\beta_{r1} + 27\beta_{c} - 6\beta_{r2} - 18\beta_{rc}},$$
  
$$M_{C}v_{L}^{2} = M_{C}v_{T}^{2} + \frac{3}{2}(\beta_{r1} + \beta_{r2}),$$
(3)

where  $M_C$  is the mass of a carbon atom. The model velocities  $v_{TA} \approx 13.3 \text{ km/s}$  and  $v_{LA} \approx 21.2 \text{ km/s}$  are very close to the experimental values of  $v_{TA} \approx 14 \text{ km/s}$  and  $v_{LA} \approx 24 \text{ km/s}.^{18}$ The elastic constants are related to the sound velocities:  $V_0 C_{66} = M_C v_T^2$  and  $V_0 C_{11} = M_C v_L^{2.25}$ 

The lowest-energy ZA acoustic (or flexure) mode shows a quadratic rather than linear dispersion near  $\Gamma$ , i.e.,  $\omega_{ZA} = q^2 \sqrt{\kappa/\rho}$ , where  $\kappa$  is a bending stiffness, and  $\rho = 4M_C/(3\sqrt{3}r_0^2)$  is the mass density. In our model the bending stiffness is given by

$$\kappa = \frac{3\sqrt{3}}{8}(\beta_v + 243\beta_p). \tag{4}$$

For the parameters of Table I,  $\kappa \approx 2.1$  eV. In Fig. 2, the calculated dispersion appears to agree well with experiment and with LDA calculations.

TABLE II. Elastic constants from the experiment and the model (in GPa). Note a relation among elastic constants (Refs. 14 and 25) for hexagonal symmetry:  $C_{66} = (C_{11} - C_{12})/2$  and  $\nu = C_{12}/C_{11}$ .

	<i>C</i> <sub>11</sub>	<i>C</i> <sub>12</sub>	C <sub>66</sub>	ν	
Experiment <sup>a</sup>	1060	180	440	0.17	
Model	1024	210	407	0.20	

<sup>a</sup>Reference 24.

TABLE III. Exact coefficients  $\alpha_i$  for the analytical expressions [Eq. (5)] of phonon energies at high-symmetry k points.

k point	Mode	$\hbar\omega$ (cm <sup>-1</sup> )	$\alpha_{r1}$	$\alpha_c$	$\alpha_v$	$\alpha_{r2}$	$lpha_p$	$\alpha_{rc}$
Г	ZO	889	0	0	54	0	0	0
	LO/TO	1588	12	27	0	-6	0	-18
М	ZA	452	0	0	6	0	1296	0
	ZO	640	0	0	24	0	648	0
	TA	740	0	12	0	0	0	0
	LA	1286	8	0	0	0	0	0
	LO	1357	4	27	0	2	0	-6
	ТО	1429	12	3	0	-6	0	-6
Κ	ZO/ZA	544	0	0	13.5	0	1093.5	0
	TA	1110	0	27	0	0	0	0
	LO/LA	1177	6	6.75	0	1.5	0	-4.5
	ТО	1487	12	0	0	-6	0	0

It is often convenient to have analytic expressions for the phonon energies at symmetry points (e.g., for verifying a numerical implementation). From Eq. (1),

$$\omega^2 = (M_C r_0^2)^{-1} \sum_i \alpha_i \beta_i, \qquad (5)$$

where the index *i* runs over (r1, c, v, r2, p, rc) and coefficients  $\alpha_i$  are given in Table III.

Turning from graphene to carbon nanotubes, we calculate the RBM for tubes of different diameter and chirality. This mode corresponds to a radial stretching or compression of the tube. The mode emerges from the lowest-energy acoustic phonon modes in graphene. The RBM acquires finite energy at zero wave vector due to the nanotube curvature, with a simple  $\approx 1/d$  scaling of energy with diameter. As a result, RBM measurements are widely used to identify the diameters of single-walled carbon nanotubes.<sup>26</sup>

For a given tube, we first relax the atomic positions and allow the lattice constant to adjust to minimize the energy. We then calculate the RBM energy. The results for all tubes in the diameter range from 0.5 to 4.0 nm are shown in Fig. 3. Simple scaling arguments based on continuum elasticity suggest that RBM energies should scale with diameter as  $\hbar\omega_{RBM}=A/d$ . Experimental data are typically fitted with the phenomenologically adapted form  $\hbar\omega_{RBM}=A/d+B$ . For tubes of d=1 nm, experimental phonon energies A+B are reported in the range of 226–248 cm<sup>-1</sup>,<sup>27–33</sup> while *ab initio* calculations suggest A+B=234 or 226 cm<sup>-1</sup>.<sup>27,32</sup> The constant offset was reported in the range from B=-6 cm<sup>-1</sup> to B=27 cm<sup>-1</sup>. Recently, it was reported<sup>33</sup> that a nonzero offset *B* is caused by the interaction with a substrate, while for freely suspended nanotubes *B* should be zero.

Within our model, the RBM mode shows accurate A/dscaling independent of chirality, with  $B \approx 0$  and  $A \approx 225$  cm<sup>-1</sup> (where *d* is in nm) as shown in Fig. 3. From the theory of elasticity,  $A = 2\hbar v_L$ , which gives  $A \approx 225$  cm<sup>-1</sup> for the parameters of Table I, in accord with



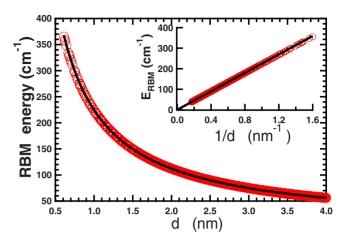


FIG. 3. (Color online) Radial breathing mode (RBM) energy as a function of tube diameter (red open circles) along with the best fit  $\hbar \omega_{RBM}$ =224.6 cm<sup>-1</sup>/*d* (black solid curve). The inset shows the same results versus inverse diameter.

the numerical result. The model is in good agreement with the most recent experimental<sup>33</sup> and theoretical<sup>32</sup> values of A=227 and A+B=226 cm<sup>-1</sup> respectively.

In general, a valence force model will have some anharmonicity. Since we have not attempted to fit experimental or *ab initio* anharmonicities, any anharmonicities are likely to be unphysical. It is therefore desirable to minimize the anharmonicity in the model, and the form of Eq. (1) is designed with this in mind. One measure of anharmonicity is the Gruneisen parameter  $\gamma = -(2\omega)^{-1}(d\omega/d\varepsilon)$ , which represents the fractional shift in phonon frequency  $\omega$  when the crystal is subjected to a strain  $\varepsilon$  in all directions. For the doubly degenerate  $E_{2g}$  phonon mode in graphene, our model gives  $\gamma_{E_{2g}} \approx -0.2$ . This is much smaller in magnitude than the experimental value of  $\gamma_{E_{2g}} \approx 2.0,^{13,34}$  confirming that our model is relatively harmonic in this respect.

For nanotubes, we have another form of anharmonicity: the phonon shifts due to bending of the graphene sheet. We have calculated the shifts in LO and TO phonons relative to graphene. The TO mode shift is less than  $12 \text{ cm}^{-1}/d^2$  in our model (where *d* is in nm) and the LO mode and the LO-TO splitting are even less. Experimental shifts are four times larger in semiconducting nanotubes,<sup>35</sup> confirming that our model successfully minimizes any unintended anharmonicities.

In conclusion, we have developed a valence force model applicable for  $sp^2$ -carbon-based structures. Our model gives a good fit of the graphene phonon dispersion and elastic constants, and describes well the RBM energy of nanotubes. The model also avoids the unphysical strong anharmonicities that occur in some valence force models. Most importantly, in contrast to other phonon models for  $sp^2$ -bonded carbon, Eq. (1) makes no reference to an underlying lattice, so it can be directly applied to distorted geometries.

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